Vishay Semiconductors

Schottky Rectifier, 2 x 6 A



Base common cathode

04

02

Common

cathode

D-PAK (TO-252AA)

2 x 6 A

60 V

0.57 V

35 mA at 125 °C

150 °C

Common cathode

7 mJ

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Anode

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Anode

FEATURESPopular D-PAK outline

- Center tap configuration
- Small foot print, surface mountable
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Compliant to RoHS Directive 2002/95/EC
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C

DESCRIPTION

The VS-12CWQ06FNPbF surface mount, center tap, Schottky rectifier series has been designed for applications requiring low forward drop and small foot prints on PC board. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
I _{F(AV)}	Rectangular waveform	12	A		
V _{RRM}		60	V		
I _{FSM}	t _p = 5 μs sine	320	A		
V _F	6 Apk, T _J = 125 °C (per leg)	0.57	V		
TJ	Range	- 55 to 150	°C		

VOLTAGE RATINGS					
PARAMETER	SYMBOL	VS-12CWQ06FNPbF	UNITS		
Maximum DC reverse voltage	V _R	60	V		
Maximum working peak reverse voltage	V _{RWM}	00			

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average per leg			6	А	
See fig. 5 per device	I _{F(AV)}	50% duty cycle at $T_{\rm C} = 151$ C, rectangular wavelonn		12	~
Maximum peak one cycle non-repetitive surge current	I _{FSM}	5 µs sine or 3 µs rect. pulse	Following any rated load condition and with	320	A
See fig. 7		10 ms sine or 6 ms rect. pulse	rated V_{RRM} applied	105	
Non-repetitive avalanche energy per leg	E _{AS}	T _J = 25 °C, I _{AS} = 1.2 A, L = 10 mH		7	mJ
Repetitive avalanche current per leg	I _{AR}	Current decaying linearly to zero in 1 μs Frequency limited by T_J maximum V_A = 1.5 x V_R typical		0.8	А

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www.vishay.com

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D-PAK (TO-252AA)

PRODUCT SUMMARY

Package

I_{F(AV)}

 V_R

V_F at I_F

I_{RM}

T_{.1} max.

Diode variation

 E_{AS}

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ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop per leg See fig. 1		6 A	T 05 %C	0.61	V
	V (1)	12 A	T _J = 25 °C	0.79	
	V _{FM} ⁽¹⁾	6 A	T 105 %C	0.57	
		12 A	—— T _J = 125 °C	0.72	
Maximum reverse	I _{BM} ⁽¹⁾	T _J = 25 °C	$V_{\rm B} = \text{Rated } V_{\rm B}$	3	mA
leakage current per leg See fig. 2	'RM ''	T _J = 125 °C	VR = naleu VR	35	
Threshold voltage	V _{F(TO)}	$T_{\rm J} = T_{\rm J}$ maximum		0.36	V
Forward slope resistance	r _t			24.14	mΩ
Typical junction capacitance per leg	CT	V_{R} = 5 V_{DC} , (test signal range 100 kHz to 1 MHz), 25 °C		360	pF
Typical series inductance per leg	L _S	Measured lead to lead 5 mm from package body		5.0	nH

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 $\,\%$

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range		T_{J} ⁽¹⁾ , T_{Stg}		- 55 to 150	°C
Maximum thermal resistance, junction to case	per leg	- R _{th-IC}	DC operation See fig. 4	3.0	°C/W
	per device			1.5	
Approximate weight				0.3	g
				0.01	oz.
Marking device			Case style D-PAK (similar to TO-252AA)	12CW0	206FN

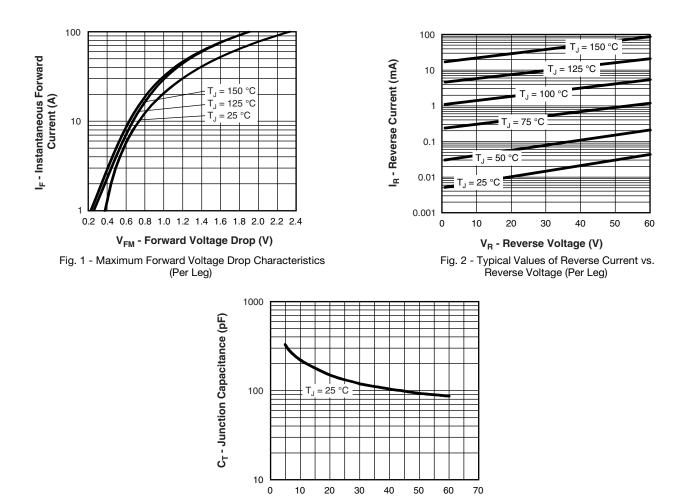
Note

(1) $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$ thermal runaway condition for a diode on its own heatsink



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V_R - Reverse Voltage (V) Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

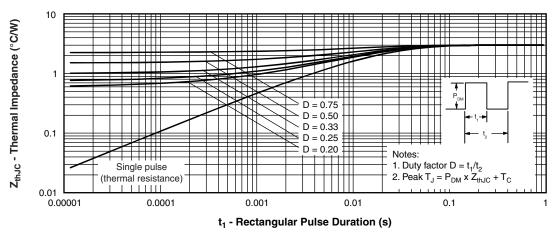
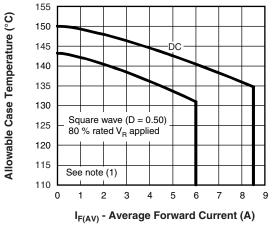


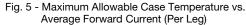
Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)

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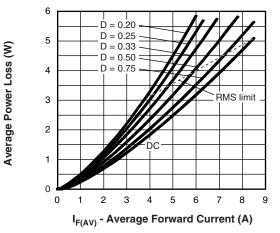


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

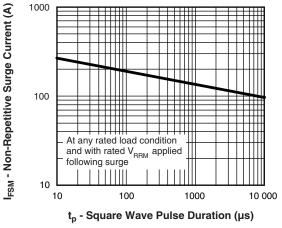


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

Note

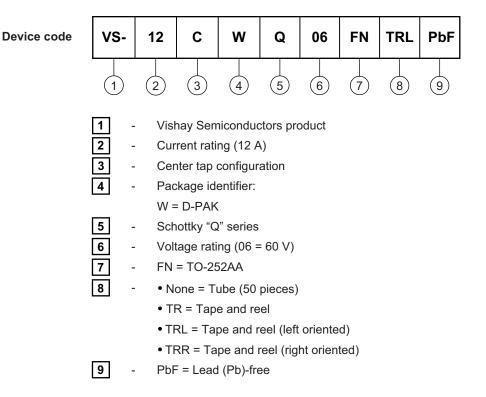
- ⁽¹⁾ Formula used: $T_C = T_J (Pd + Pd_{REV}) \times R_{thJC}$;
- $\begin{array}{l} \mathsf{Pd} = \mathsf{Forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \ x \ \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see fig. 6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{Inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \ x \ \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{80} \ \% \ \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$



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ORDERING INFORMATION TABLE



LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95016			
Part marking information	www.vishay.com/doc?95059			
Packaging information	www.vishay.com/doc?95033			
SPICE model	www.vishay.com/doc?95278			



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